



Artificial pinning centers created by Fe₂O₃ coating on MgB₂ thin films

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Abstract

MgB₂ thin films were fabricated on MgO (1 0 0) single crystal substrates. First, deposition of boron was performed by rf magnetron sputtering on MgO substrates and followed by a post-deposition annealing at 850°C in magnesium vapor. In order to investigate the effect of Fe₂O₃ nanoparticles on the structural and magnetic properties of films, MgB₂ films were coated with different concentrations of Fe₂O₃ nanoparticles by spin coating process. The magnetic field dependence of the critical current density J_c was calculated from the M–H loops and also magnetic field dependence of the pinning force density $f_p(b)$ was investigated for the films containing different concentrations of Fe₂O₃ nanoparticles. The critical current density J_c was found to be around $1.8 \times 10^6 \text{ A/cm}^2$ and $1.3 \times 10^6 \text{ A/cm}^2$ for the films with the concentration of 50% and 33% Fe₂O₃, respectively. It was found that the films coated with Fe₂O₃ nanoparticles have slightly enhanced critical current density.